

Substitute for form 1449A&B/PTO <b>INFORMATION DISCLOSURE          STATEMENT BY APPLICANT</b> <i>(use as many sheets as necessary)</i>				<i>Complete if Known</i>	
				Application Number	10/509656
				Filing Date	
				First Named Inventor	Toshio Goto
				Art Unit	
Examiner Name					
Sheet	1	of	1	Attorney Docket Number	

U.S. PATENT DOCUMENT					
Examiner Initials*	Cite No. <sup>1</sup>	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Number	Kind Code <sup>2</sup> (if known)		
		US			
		US			
		US			

FOREIGN PATENT DOCUMENT							
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document			Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Translation <sup>6</sup>
		Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)			
✓		JP	06-293960	A	10-21-1994	MATSUSHITA ELECTRIC IND CO LTD	Abstract
✓		JP	3162623	B	02-23-2001	TOKYO ELECTRON LTD	Abstract
✓		JP	04-053947	B	08-28-1992	NIPPON STEEL CORP	Abstract
✓		JP	04-081132	B	12-22-1992	HOKAIDO UNIV	Abstract
✓		JP	10-083893	A	03-31-1998	SONY CORP	Abstract
✓		JP	62-054871	B	11-17-1987	AGENCY OF IND SCIENCE & TECHNOL	Abstract

OTHER PRIOR ART-NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	Translation <sup>6</sup>
✓		Kono et al., "Plasma Absorption Spectroscopy Using Microdischarge Light Source" (May 2000)	Abstract
✓		Ohta et al., "Behaviors of Si, SiF, SiF <sub>2</sub> radicals and SiF <sub>4</sub> molecule in RF60MHz capacitively coupled SiF <sub>4</sub> plasma", Proceedings of International Symposium on Dry Process, The Institute of Electrical Engineer of Japan, October 10 - 11, 2002	Abstract
✓		Ohta et al., "The effect of driving frequency on the behavior of Si atoms in capacitively coupled VHF SiF <sub>4</sub> plasma", Proceedings of the 20 <sup>th</sup> Symposium on Plasma Processing, Division of Plasma Electronics, The Japan Society of Applied Physics, January 29 - 31, 2003	Abstract

Examiner Signature		Date Considered	12-22-06
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				First Named Inventor	
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Examiner Name				Toshio Goto	
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		US			
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Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	Translation <sup>6</sup>
R		Kikukawa et al., "Microcrystalline Silicon Thin Film Formation Using a Low Pressure Microwave Plasma", the 62 <sup>nd</sup> Symposium of the Society of Applied Physics, Digest 14a-ZF-3, September 2001, pp. 736	

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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet

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of

1

**Complete if Known**

Application Number	10/509,656
Filing Date	September 29, 2004
First Named Inventor	Toshio GOTO
Art Unit	2812
Examiner Name	Unassigned
Attorney Docket Number	101250.55460US

U.S. PATENT DOCUMENTS

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